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# 2SA1381/KSA1381 PNP Epitaxial Silicon Transistor

## Applications

- Audio, Voltage Amplifier and Current Source
- CRT Display, Video Output
- General Purpose Amplifier

#### Features

- High Voltage : V<sub>CEO</sub>= -300V
- Low Reverse Transfer Capacitance : C<sub>re</sub>= 2.3pF at V<sub>CB</sub> = -30V
- Excellent Gain Linearity for low THD
- High Frequency: 150MHz
- Full thermal and electrical Spice models are available
- Complement to 2SC3503/KSC3503

# Absolute Maximum Ratings\* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
BV <sub>CBO</sub>	Collector-Base Voltage	-300	V
BV <sub>CEO</sub>	Collector-Emitter Voltage	-300	V
BV <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current(DC)	-100	mA
I <sub>CP</sub>	Collector Current(Pulse)	-200	mA
P <sub>C</sub>	Total Device Dissipation, $T_C=25^{\circ}C$ $T_C=125^{\circ}C$	7 1.2	W W
T <sub>J</sub> , T <sub>STG</sub>	Junction and Storage Temperature	- 55 ~ +150	°C

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### Thermal Characteristics\* T<sub>a=25°C</sub> unless otherwise noted

Symbol	Parameter	Max.	Units
$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	17.8	°C/W

\* Device mounted on minimum pad size

### h<sub>FE</sub> Classification

Classification	С	D	E	F
h <sub>FE</sub>	40 ~ 80	60 ~ 120	100 ~ 200	160 ~ 320



2SA1381/KSA1381 — PNP Epitaxial Silicon Transistor

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_{C} = -10\mu A, I_{E} = 0$	- 300			V
BV <sub>CEO</sub>	Collecto- Emitter Breakdown Voltage	I <sub>C</sub> = - 1mA, I <sub>B</sub> = 0	- 300			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_{E} = -10\mu A, I_{C} = 0$	- 5			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = -200V, I_{E} = 0$			- 0.1	μA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = -4V, I_{C} = 0$			- 0.1	μA
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = - 10V, I <sub>C</sub> = - 10mA	40		320	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = - 20mA, I <sub>B</sub> = - 2mA			- 0.6	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = - 20mA, I <sub>B</sub> = - 2mA			- 1	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = - 30V, I <sub>C</sub> = - 10mA		150		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = - 30V, f = 1MHz		3.1		pF
C <sub>re</sub>	Reverse Transfer Capacitance	V <sub>CB</sub> = - 30V, f = 1MHz		2.3		pF

#### . ... . ...

\* Pulse Test: Pulse Width $\leq$ 300µs, Duty Cycle $\leq$ 2%

# **Ordering Information**

Part Number*	Marking	Package	Packing Method	Remarks
2SA1381CSTU	2SA1381C	TO-126	TUBE	hFE1 C grade
2SA1381DSTU	2SA1381D	TO-126	TUBE	hFE1 D grade
2SA1381ESTU	2SA1381E	TO-126	TUBE	hFE1 E grade
2SA1381FSTU	2SA1381F	TO-126	TUBE	hFE1 F grade
KSA1381CSTU	A1381C	TO-126	TUBE	hFE1 C grade
KSA1381DSTU	A1381D	TO-126	TUBE	hFE1 D grade
KSA1381ESTU	A1381E	TO-126	TUBE	hFE1 E grade
KSA1381FSTU	A1381F	TO-126	TUBE	hFE1 F grade

\* 1. Affix "-S-" means the standard TO126 Package (see package dimensions). If the affix is "-STS-" instead of "-S-", that mean the short-lead TO126 package. 2. Suffix "-TU" means the tube packing, The Suffix "TU" could be replaced to other suffix character as packing method.

#### **Typical Characteristics** = -140µA = -120µA I, [A], COLLECTOR CURRENT -16 collector current = -100µA = -80µA -12 = -60µA = -40µA = -20μA $I_{\mu} = 0\mu A$ -1 -2 -8 -10 $V_{ce}[V]$ , COLLECTOR-EMITTER VOLTAGE Figure 1. Static Characteristic 11 $V_{CE} = -10V$

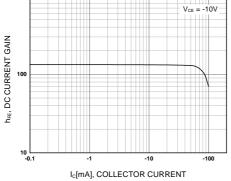


Figure 3. DC current Gain

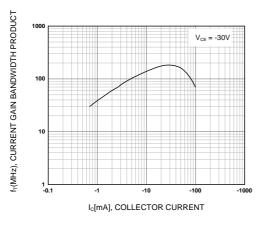


Figure 5. Current Gain Bandwidth Product

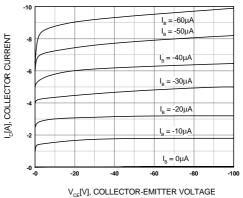


Figure 2. Static Characteristic

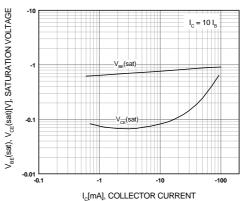
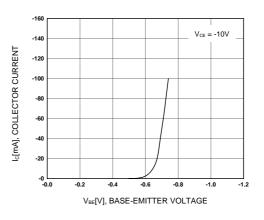


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage





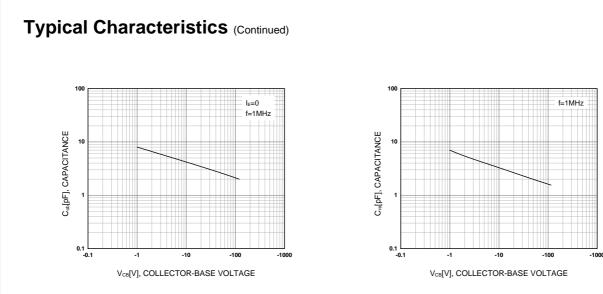
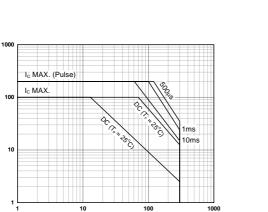


Figure 7. Collector Output Capacitance



V<sub>CE</sub>[V], COLLECTOR-EMITTER VOLTAGE

Figure 8. Reverse Transfer Capacitance

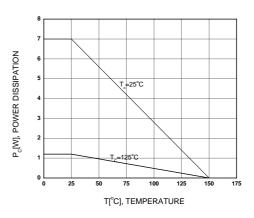
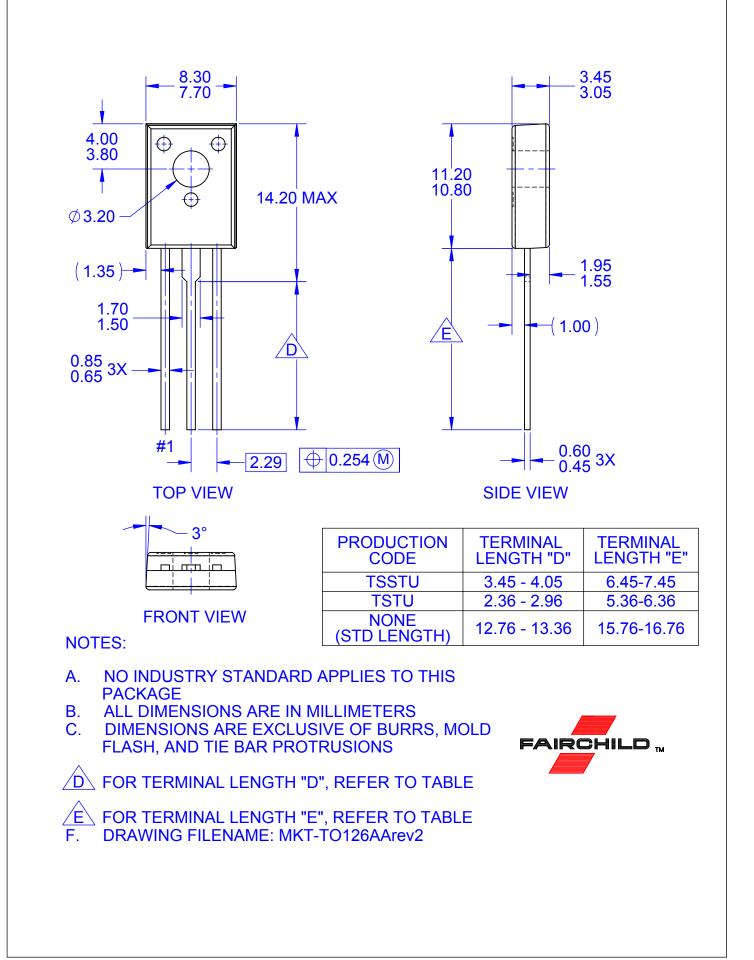


Figure 10. Power Derating

Ic[mA], COLLECTOR CURRENT



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